Advanced Vitreous State - The Physical Properties of Glass



Dielectric Properties of Glass Lecture 1: Dielectric in Static Field

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Resources

- Fundamental of Inorganic Glasses, A.K.
 Varshneya, Soc. Glass Tech, 2006
- Principles of Electronic Materials and Devices by S. Kasap, 3rd Ed., McGraw Hill, 2006. Source of colored diagrams. Recommended for clear, concise description.
- Dielectric and Waves, A.R. von Hippel, John Wiley, 1954
- Engineering Dielectrics, Vol. IIA, R. Batnikas and R.M. Eichhorn, eds. ASTM STP 783, 1983

What is a dielectric?

 Dia+electric i.e. poorly electric and can sustain electric field without appreciable current.

Uses:

- Insulation for wires, cables, electrical equipment
- Capacitors
- Devices for propagation of e.m. waves
- (Piezoelectric transducers, time devices)
- (Memory elements)
- Microelectronics

Dielectrics in microelectronics:

(a) Gate dielectrics, (b) Tunneling oxides in memory devices, (SiO_xN_y)
(c) Capacitors, (d) Interconnect dielectrics, (e) Isolation dielectrics



Electronic and Ionic polarizations are most important.

Principal Dielectric Properties: Why bother?

- 1. <u>Dielectric constant, ε'</u>
 - High for charge storage device e.g. capacitor, gate dielectric
 - Low for faster signal transmission (speed ~ $1/\sqrt{\epsilon}$)
- 2. <u>Dielectric (energy) loss, ε</u>"
 - High for microwave heating
 - Low for signal transmission
- 3. <u>Dielectric breakdown</u>
 - High for most insulating applications e.g. tunneling oxides
 - Low for fuses (?)

Rigid insulators: glass, ceramics, porcelain, epoxies..

- Advantages of glass & ceramics over polymers
 - Superior dielectric properties
 - No creep or deformation at RT
 - Greater stability in hostile environment
- Other desirable characteristics
 - Suitable thermal and mechanical properties
 - Ability to form seals with metals/ceramics
 - No porosity

How can we understand this?



Note that the addition of alkali oxide to silica increases the MHz-GHz frequency dielectric constant monotonically.
The increase is higher for the larger alkali.

FIGURE 154. Dielectric constant ε of binary alkali silicate glasses at $4.5 \cdot 10^8$ Hz and room temperature, from Appen and Bresker [26].



(a) Parallel plate capacitor in vacuum.
(b) As a slab of insulating material is inserted between the plates, there is an external current flow indicating that more charge is stored on the plates. $Q_o \propto V$ = $C_o V$

 Q_o = charge on the plates

V = voltage

 C_o = capacitance of a parallel plate capacitor in free space.

Units: Coulomb/Volt = Farad

 $C_o \propto$ Area of plates (neglect edge effect) \propto 1/separation between the plates = $\epsilon_0 \text{ A/d}$

 $\varepsilon_0 = 8.854 \times 10^{-12} \text{ F/m}$

Capacitance of a dielectric



$$\varepsilon_r = \frac{Q}{Q_o} = \frac{C}{C_o}$$

 ε_r = relative permittivity,

Q = charge on the plates with a dielectric medium > Q_o

So that $C > C_o$ and $\varepsilon_r > 1.0$

<u>Goal</u>: Understand the origin of ε_r and manipulate its value by material design.

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Coulomb's law and electric field

Force between two charges <u>in vacuum</u>: $F_0 = q_1 q_2 / 4\pi\epsilon_0 r^2$ Coulomb's law – Proven to better than 2 ppb

Electric field in vacuum, $\mathbf{E}_{0} = q_{1}/4\pi\epsilon_{0}r^{2}$ Force between two charges <u>in dielectric</u>: $\mathbf{F} = q_{1} q_{2}/4\pi\epsilon_{0}\epsilon_{r}r^{2}$ Electric field in dielectric, $\mathbf{E} = q_{1}/4\pi\epsilon_{0}\epsilon_{r}r^{2}$

The field in dielectric is reduced by ϵ_r .

The dielectric is not neutral, but must have non-uniform charge \Rightarrow charges are shifted as the dielectric gets polarized.

Displaced charge produces electrical force given by displacement vector $D = \varepsilon_0 \varepsilon_r E$, so that in general ε_r is a tensor (of course, scalar for glass).

Dielectric constant is a macroscopic/engineering property!

Polarization in general!



Former President Bill Clinton warned Saturday that the country is becoming increasingly polarized despite the historic nature of the Democratic primary.



Microscopic view:

The simplest unit of polarization: Dipole, where positive charge is displaced with respect to its countercharge.

Define dipole moment:

p = charge x **separation** (-Q to +Q)



Define polarization P = dipole moment / volume

For small fields: $\mathbf{p} \propto \mathbf{E}_{loc}$ or $\mathbf{p} = \alpha \mathbf{E}_{loc}$, where α is polarizability and \mathbf{E}_{loc} is local electric field acting on the specific dipole. If there are N dipoles/vol, $\mathbf{P} = N\mathbf{p} = N\alpha \mathbf{E}_{loc}$

Dielectric susceptibility, χ

Experimentally, $\mathbf{P} \propto \mathbf{E}$, so that $\mathbf{P} = \chi \mathbf{E}$ χ is dielectric susceptibility; describes the bulk response of the material.

Two sources of charge on the plates:

- (i) Charge from connection to the battery
- (ii) Charge induced by the bound charge from the polarization of the dielectric. This *bound* surface charge/area = P

$$D = D_0 + P = \varepsilon_0 \mathbf{E} + \chi \mathbf{E}$$

Also **D** = $\varepsilon_0 \varepsilon_r \mathbf{E}$

So that $\chi = \varepsilon_0(\varepsilon_r-1)$



Figure 15-1. (a) A parallel plate capacitor connected to a potential difference *V*. With vacuum between the plates, the electric displacement is $D_0(=$ charge *q*). The flux lines start from the + charges on the positive plate and end on the – charges on the negative plate. (b) Upon introducing a dielectric between the plates, polarization charges +/–P appear on the dielectric facing the plates. This causes the charges on the plates to become (q+P) and –(q+P). Inset shows exaggeration of the plate– nearest dielectric face region. (Adapted after B. K. P. Scaife, *Principles of Dielectrics*,



Polarization Mechanisms

Electronic polarization
 Ionic/atomic polarization
 Dipolar/orientational polarization

 Jellyfish' polarization
 Interfacial polarization

Nature has two types of processes: relaxation or resonance. 1 and 2 are resonance processes 3 and 4 are relaxation processes



http://hypertextbook.com/physics/electricity/dielectrics/stretching.html



• α_{e} is ~T independent.

Use high Z elements to increase refractive index of a glass.

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Electronic polarizability

General remarks - ***tips for material design***:

α_e determines n in the visible region, and at lower freq.
 In a given column α_e increases with atom radius.
 α_e for anions >> for cations.

He(0.201)

Note: Above α_e values are by Pauling and Tessman et al. Others have given different values, depending on the compositions used for self-consistency (see Kittel, p.391).



 a_i depends on the bonding between cation and anion – more difficult to model when bonding is complex as in solids with mixed bonding.

 $lpha_i$ is also ~ T independent (if structure does not change). $lpha_0$ is in the IR – why?

It depends on reduced ion mass (μ) << m_e (also bonding).

High (but <optical) frequency dielectric constant

At frequencies below the resonance of ionic polarization, both electronic and ionic polarizations will contribute to dielectric constant. Claussius Mossotti equation gives for glass.

$$\frac{\varepsilon_r - 1}{\varepsilon_r + 2} = \frac{1}{3\varepsilon_o} (N_e \alpha_e + N_i \alpha_i)$$

Additional mechanisms like dipolar, interfacial and interfacial polarization may also contribute.

Dipolar/orientational polarization of a polar gas



- A gas of permanent dipoles has zero polarization due to their random orientation.
- In E, dipoles feel a torque that tries to align the dipoles parallel to E, which is balanced by thermal agitation. The result is a net dipole moment that ↑ or ↓ as T↑?

Dipoles in a field



Energy of a dipole= $\mathbf{p_0} \cdot \mathbf{E} = \mathbf{p_0} \mathbf{E} \cos \theta$



Integration gives a Langevin function L(x)

 $x = p_o E/kT$

 $p_{av} = p_o L(x) = p_o \operatorname{coth} (x-1/x)$; where $x = p_o E/kT$

At low E, typical of common use, L(x) = x/3. Then, $p_{av} = p_o^2 E/3kT$ or $\alpha_{dipolar} = p_o^2/3kT$

Interfacial polarization



In the presence of an applied field, the mobile positive ions migrate toward the negative electrode and collect there leaving behind negative charges in the dielectric. The dielectric therefore exhibits interfacial polarization. Since it arises from the migration of charge to much larger distances, the polarization is orders of magnitude larger than from other mechanisms.

Glasses do not have interfaces \Rightarrow Not an important mechanism for glass. However, glasses are often ionic conductors. So interfacial polarization will develop if the charge carrier can not ??

freely exchange at the electrodes.

Dielectric constant of oxide glasses

Oxygen, being the anion, is most easily polarized.

Non-bridging oxygen is even more polarizable than bridging oxygen.

✤With decreasing field strength of the modifier cation, the M⁺-NBO⁻ bond can be polarized more easily. The same trend is observed with alkaline earth cations.

Colculation of dialoctric			
constant from composition	Li ₂ O Na ₂ O K ₂ O		
Often dielectric constant is additive, and therefore can be estimated from composition (when structural changes are small or monotonic). The Table is for ε_r at RT and 0.45 GHz, as obtained by Appen & Bresker (1952).	BeO MgO CaO SrO BaO B_2O_3 Al_2O_3 SiO ₂ TiO ₂		
$\varepsilon = \frac{1}{100} \sum \varepsilon_i p_i,$	ZnO CdO PbO MnO		

	p,	is	mole%	of ith	¹ com	ponent
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From Glass by H. Scholze

Oxide	Factor
Li ₂ O	14.0 (15.0) ^a
Na ₂ O	17.6 (17.6) ^a
K ₂ O	16.0 (20.3) ^a
BeO	13.8
MgO	15.4
CaO	17.4
SrO	18.0
BaO	20.5
B ₂ O ₃	3 · · · 8 ^b
Al_2O_3	9.2
SiO ₂	3.8
TiO ₂	25.5
ZnO	14.4
CdO	17.2
РЬО	22.0
MnO	13.8
FeO	16.0
CoO	15.2
NiO	13.4

^a The values in parentheses are valid for the binary R_2O —SiO₂ glasses.

^b The factor of B_2O_3 is dependent on the glass composition.

Dielectric constant of Na₂O xAl₂O₃(3-2x)SiO₂



(b)



FIG. 4. Intermediate-frequency dielectric constant of the SAS glasses at 25 °C.

Hsieh, Jain, Kamitsos, J Appl Phys (1996)

FIG. 7. Environment of a sodium ion consisting of: (a) bridging and nonbridging oxygen atoms in sodium trisilicate glass, and (b) bridging and nonbridging oxygen atoms as well as aluminum tetrahedra in SAS glass. δ and δ' are charges on sodium ions in respective glasses with $\delta' > \delta$.

(a)

Structural origin of ε_r of oxide glasses



FIG. 8. Correlation between the electronic polarizability of oxygen ions and the O 1s XPS binding energy in the SAS glasses.

FIG. 9. Correlation between the ionic polarizability of sodium ions and the Na 1s XPS binding energy in the SAS glasses.

Why is this polar bear worried?





FIGURE 102. Indexes of refraction n_D of binary alkali silicate glasses, from various authors.

Local field in a dielectric, E_{loc}

Fig. 18.3 Kingery??

$$\mathsf{E}_{\mathsf{loc}} = \mathsf{E}_{\mathsf{ext}} + \mathsf{E}_1 + \mathsf{E}_2$$

Field due to spherical cavity, $E_1 = P/3\varepsilon_0$ Field due to individual dipoles, $E_2 = zero$ for glass with random distribution

Local or Lorenz field, $E_{loc} = E_{ext} + P/3\varepsilon_0 = E_{ext} (\varepsilon_r + 2)/3$

Claussius-Mossotti Eq. $\alpha = (3\epsilon_0 / N) (\epsilon_r - 1) / (\epsilon_r + 2)$